V.P. & R.P.T.P SCIENCE COLLEGE

INTERANAL EXAM-2017

S.Y.B.Sc. (4TH SEM) ELECTRONICS - US04CELE01

Date -09/03/2017 Time:-3:00 pm to 4:30 pm

Q-1	Choose correct answer		[3]
1.	The capacitance between connecting wires and ground is called		[-]
	(A)stray capacitance	(C) inductance	11
	(B) resistance	(D) none of above	P. Scien
2.	Self bias FET biasing circuit is	, than fix bias circuit.	
	(A) good	(C) not botton	IBRARY
	(B) not good	(D) none of above	IDNAK
3.	bias type of biasing is used in common source amplifier circuit.		
	(A) potential divider	(C) self	V. Naga
	(B) fixed	(D) none of above	
Q-2	Short answer type question.(attempt any two)		[4]
1.	List different FET parameters.		[-1]
2.	Draw the self bias circuit for n-channel FET.		
3.	Draw the input and output wave form for common source amplifier circuit.		
Q-3	Draw the frequency response curv	ve for transistor amplifier and explain it. And	[6]
	also explain why the gain of an amplifier false off at upper and lower		
	frequency ends.	, and to the	
		OR	
Q-3	Give an account of fixed voltage bias circuit for FET.		[6]
Q-4	Draw the potential divider biasing circuit for n-channel FET, and explain its		[6]
	working.		8.5
Laconia.		OR	
Q-4	Give an account of n-channel enhancement MOSFET.		[6]
Q-5	Draw a neat circuit diagram for common source amplifier circuit, and explain		[6]
	its working in detail with necessary waveforms.		
		OR	
Q-5	Draw a neat circuit diagram for common drain amplifier circuit, and explain its working in detail with necessary waveforms.		[6]
